

# 1A Ultra Low Dropout Linear Regulator with Programmable Current Limiting

### ISL80121-5

The ISL80121-5 is a low dropout voltage, single output LDO with programmable current limiting. This LDO operates from input voltages of 2.2V to 6V. The ISL80121-5 has a nominal output voltage of 5V. Other custom voltage options are available upon request.

A sub-micron BiCMOS process is utilized for this product family to deliver the best in class analog performance and overall value. The programmable current limiting improves system reliability of applications. An external capacitor on the soft-start pin provides an adjustable soft-starting ramp. The ENABLE feature allows the part to be placed into a low quiescent current shutdown mode.

This CMOS LDO will consume significantly lower quiescent current as a function of load compared to bipolar LDOs, which translates into higher efficiency and packages with smaller footprints. Quiescent current is modestly compromised to achieve a very fast load transient response.

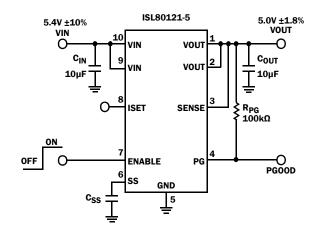
### **Features**

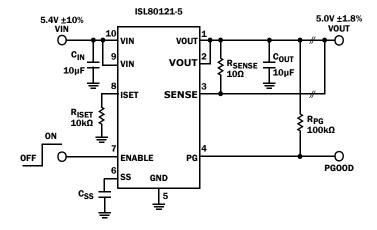
- ±1.8% V<sub>OUT</sub> Accuracy Guaranteed Over Line, Load and T<sub>I</sub> = -40 °C to +125 °C
- Very Low 130mV Dropout Voltage at V<sub>IN</sub> = 5.0V
- High Accuracy Current Limit Programmable up to 1.75A
- · Very Fast Transient Response
- 200µV<sub>RMS</sub> Output Noise
- · Power Good Output
- · Programmable Soft-starting
- · Over-Temperature Protection
- Small 10 Ld DFN Package

### **Applications**

- · USB devices
- · Telecommunications and Networking
- · Medical Equipment
- · Instrumentation Systems
- · Routers and Switchers
- Gaming

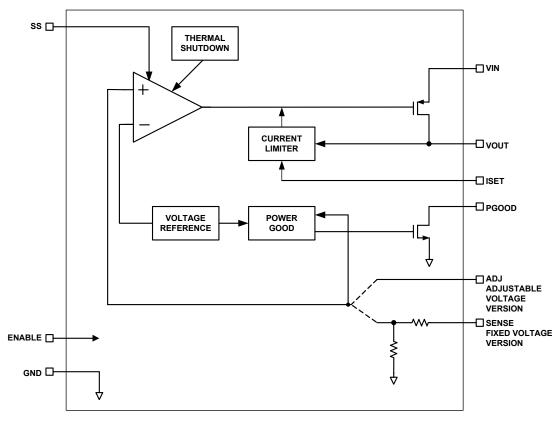
### **Typical Applications**





$$I_{LIMIT} = 0.75 + \frac{2.9}{R_{SET}(k\Omega)}$$

### **Block Diagram**



## **Ordering Information**

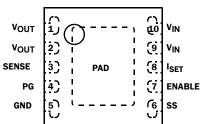
PART NUMBER	PART	V <sub>OUT</sub> VOLTAGE	TEMP. RANGE	PACKAGE	PKG
(Notes 1, 2, 4)	MARKING	(Note 3)	(°C)	(Pb-Free)	DWG. #
ISL80121IR50Z	DZAD	5.0V	-40 to +125	10 Ld 3x3 DFN	L10.3x3

#### NOTES:

- 1. Add "-T\*" suffix for tape and reel. Please refer to TB347 for details on reel specifications.
- 2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
- 3. The 1.5V, 3.3V and 5V fixed output voltages will be released in the future. Please contact Intersil Marketing for more details.
- 4. For Moisture Sensitivity Level (MSL), please see device information page for ISL80121-5. For more information on MSL, please see Technical Brief TB363.

# **Pin Configuration**

ISL80121-5 (10 LD 3x3 DFN) TOP VIEW



# **Pin Descriptions**

PIN NUMBER	PIN NAME	DESCRIPTION	
1, 2	V <sub>OUT</sub>	Output voltage. A minimum 10µF X5R/X7R output capacitor is required for stability. See "External Capacitor Requirements" on page 8 in the "Functional Description" for more details.	
3	SENSE Remote voltage sense for internally fixed V <sub>OUT</sub> options. Parasitic resistance between the V <sub>OUT</sub> pin an causes small voltage drops which degrade V <sub>OUT</sub> accuracy. For applications that require a stiff V <sub>OUT</sub> , or sense pin to the load.		
4	PG	V <sub>OUT</sub> in regulation signal. Logic low indicates V <sub>OUT</sub> is not in regulation, and must be grounded if not used.	
5	GND	Ground.	
6	SS	External capacitor adjusts in-rush current.	
7	ENABLE	V <sub>IN</sub> -independent chip enable. TTL and CMOS compatible.	
, , , , , , , , , , , , , , , , , , ,		Current limit setting. Current limit is 0.75mA when this pin is left floating. This default value can be increased by tying RSET to GND, or decreased by tying RSET to VIN. See "Programmable Current Limit" on page 7 in the "Functional Description" for more details. Do not short this pin to ground.	
9, 10	V <sub>IN</sub>	Input supply. A minimum of 10µF X5R/X7R input capacitor is required for stability. See "External Capacitor Requirements" on page 8 in "Functional Description" for more details.	
-	EPAD	EPAD at ground potential. Soldering it directly to GND plane is optional.	

#### **Absolute Maximum Ratings** (Note 7)

V <sub>IN</sub> Relative to GND	0.3V to +6.5V
V <sub>OUT</sub> Relative to GND	0.3V to +6.5V
PG, ENABLE, SENSE, SS, ISET	
Relative to GND	0.3V to +6.5V
ESD Rating	
Human Body Model (Tested per JESD22-A114)	2.5kV
Machine Model (Tested per JESD22-A115)	250V
Latch Up (Tested per JESD78)	±100mA @ 85°C

#### **Thermal Information**

Thermal Resistance (Typical)	$\theta_{JA}$ (°C/W)	$\theta_{JC}$ (°C/W)
10 Ld 3x3 DFN Package (Notes 5, 6)	51	7
Maximum Junction Temperature (Plastic Pac	kage)	+150°C
Storage Temperature Range	6	5°C to +150°C
Pb-Free Reflow Profile		. see link below
http://www.intersil.com/pbfree/Pb-FreeRe	eflow.asp	

Recommended Operating Conditions (Note 8)					
Junction Temperature Range (T <sub>J</sub> )	40°C to +125°C				
VIN Relative to GND	2.2V to 6V				
V <sub>OUT</sub> Range	800mV to 5V				
DO ENADIE CENCE CO ICET Deletive to CND	01/4- 61/				

PG Sink Current ...... 10mA

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

#### NOTES:

- 5. θ<sub>JA</sub> is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.
- 6. For  $\theta_{JC}$ , the "case temp" location is the center of the exposed metal pad on the package underside.
- 7. Absolute maximum voltage rating is defined as the voltage applied for a lifetime average duty cycle above 6V of 1%.
- 8. Electromigration specification defined as lifetime average junction temperature of +110 °C where max rated DC current = lifetime average current.

**Electrical Specifications** Unless otherwise noted, all parameters are established over the following specified conditions:  $V_{IN} = V_{OUT} + 0.4V$ ,  $V_{OUT} = 5.0V$ ,  $C_{IN} = C_{OUT} = 10 \mu F$ ,  $T_J = +25 \,^{\circ}$ C,  $I_{LOAD} = 0A$ . Applications must follow thermal guidelines of the package to determine worst case junction temperature. Please refer to "Functional Description" on page 7 and Tech Brief TB379. Boldface limits apply over the operating temperature range, -40  $^{\circ}$ C to +125  $^{\circ}$ C. Pulse load techniques used by ATE to ensure  $T_J = T_A$  defines established limits.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 9)	ТҮР	MAX (Note 9)	UNITS
DC CHARACTERISTICS						
DC Output Voltage Accuracy	V <sub>OUT</sub>	V <sub>OUT</sub> + 0.4V < V <sub>IN</sub> < 6V; 0A < I <sub>LOAD</sub> < 1A	-1.8		-1.8	%
DC Input Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	V <sub>OUT</sub> + 0.4V < V <sub>IN</sub> < 6.0V, V <sub>OUT</sub> = 5.0V			1	%
DC Output Load Regulation	ΔV <sub>OUT</sub>	0A < I <sub>LOAD</sub> < 1A	-1			%
Ground Pin Current	IQ	I <sub>LOAD</sub> = 0A, 2.2V < V <sub>IN</sub> < 6V		3	5	mA
		I <sub>LOAD</sub> = 1A, 2.2V < V <sub>IN</sub> < 6V		5	7	mA
Ground Pin Current in Shutdown	I <sub>SHDN</sub>	ENABLE Pin = 0.2V, V <sub>IN</sub> = 6V		0.2	12	μΑ
Dropout Voltage (Note 10)	V <sub>DO</sub>	I <sub>LOAD</sub> = 1A, V <sub>IN</sub> = 5.0V, V <sub>SENSE</sub> = 0V		90	130	mV
Output Current Limit	I <sub>LIMIT</sub>	V <sub>OUT</sub> = 4.75V, V <sub>OUT</sub> + 0.4V < V <sub>IN</sub> < 6V, ISET is floating	0.66	0.75	0.84	Α
		$V_{OUT}$ = 4.75V, $V_{OUT}$ + 0.4V < $V_{IN}$ < 6V, $R_{SET}$ = 19.33k $\Omega$		0.9		Α
Thermal Shutdown Temperature	TSD	V <sub>OUT</sub> + 0.4V < V <sub>IN</sub> < 6V		160		°C
Thermal Shutdown Hysteresis (Rising Threshold)	TSDn	V <sub>OUT</sub> + 0.4V < V <sub>IN</sub> < 6V		30		°C
AC CHARACTERISTICS	•					
Input Supply Ripple Rejection	PSRR	f = 1kHz, I <sub>LOAD</sub> = 1A		58		dB
		f = 120Hz, I <sub>LOAD</sub> = 1A		62		dB
Output Noise Voltage		I <sub>LOAD</sub> = 10mA, BW = 10Hz < f < 100kHz		210		μV <sub>RMS</sub>
ENABLE PIN CHARACTERISTICS	1					
Turn-on Threshold	V <sub>EN(HIGH)</sub>	2.2V < V <sub>IN</sub> < 6V	0.3	0.8	1.0	V
Hysteresis (Rising Threshold)	V <sub>EN(HYS)</sub>	2.2V < V <sub>IN</sub> < 6V	10	80	200	m۷

#### ISL80121-5

**Electrical Specifications** Unless otherwise noted, all parameters are established over the following specified conditions:  $V_{IN} = V_{OUT} + 0.4V$ ,  $V_{OUT} = 5.0V$ ,  $C_{IN} = C_{OUT} = 10 \mu F$ ,  $T_J = +25 \,^{\circ}$ C,  $I_{LOAD} = 0.4$ . Applications must follow thermal guidelines of the package to determine worst case junction temperature. Please refer to "Functional Description" on page 7 and Tech Brief <u>TB379</u>. **Boldface limits apply over the operating temperature range, -40 ^{\circ}C to +125 ^{\circ}C.** Pulse load techniques used by ATE to ensure  $T_J = T_A$  defines established limits. (**Continued**)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 9)	ТҮР	MAX (Note 9)	UNITS
Enable Pin Turn-on Delay	t <sub>EN</sub>	C <sub>OUT</sub> = 10μF, I <sub>LOAD</sub> = 1A		100		μs
Enable Pin Leakage Current		V <sub>IN</sub> = 6V, EN = 3V			1	μΑ
SOFT-START CHARACTERISTICS	<u>'</u>					*
Reset Pull-Down Current	I <sub>PD</sub>	EN = OV, SS = 1V	0.5	1	1.3	mA
Soft-Start Charge Current	I <sub>CHG</sub>		-3.3	-2	-0.8	μΑ
PG PIN CHARACTERISTICS	-1		<u>'</u>			•
V <sub>OUT</sub> PG Flag Threshold			75	85	92	%V <sub>OUT</sub>
V <sub>OUT</sub> PG Flag Hysteresis				4		%
PG Flag Low Voltage		I <sub>SINK</sub> = 500μA		47	100	mV
PG Flag Leakage Current		V <sub>IN</sub> = 6V, PG = 6V		0.05	1	μA

#### NOTES:

- 9. Compliance to datasheet limits is assured by one or more methods: production test, characterization and/or design.
- 10. Dropout is defined by the difference in supply  $V_{IN}$  and  $V_{OUT}$  when the output is below its nominal regulation.
- 11. Minimum capacitor of  $10\mu F$  X5R/X7R on  $V_{IN}$  and  $V_{OUT}$  required for stability.
- 12. If the current limit for in-rush current is acceptable in application, do not use this feature. Used only when large bulk capacitance required on V<sub>OUT</sub> for application.

**Typical Operating Performance** Unless otherwise noted:  $V_{IN}$  = 5.4V,  $V_{OUT}$  = 5.0V,  $C_{IN}$  =  $C_{OUT}$  = 10 $\mu$ F,  $T_J$  = +25°C,  $I_L$  = 0A.

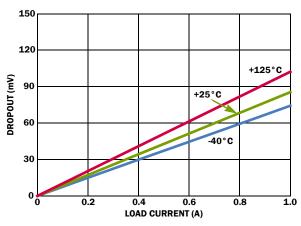


FIGURE 1. DROPOUT VOLTAGE vs LOAD

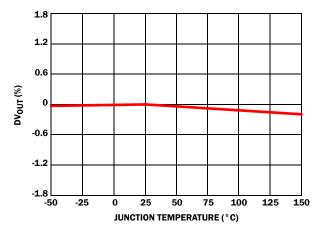


FIGURE 2. OUTPUT VOLTAGE vs TEMPERATURE

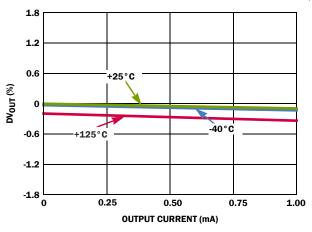


FIGURE 3. OUTPUT VOLTAGE vs OUTPUT CURRENT

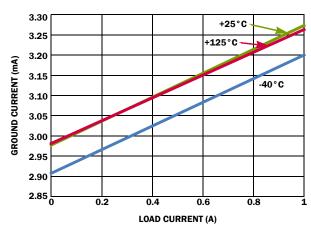


FIGURE 4. GROUND CURRENT vs LOAD CURRENT

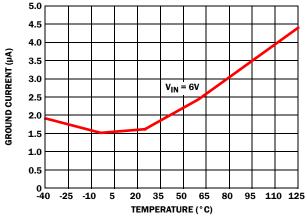


FIGURE 5. SHUTDOWN CURRENT vs TEMPERATURE

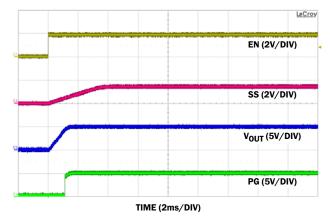


FIGURE 6. ENABLE START-UP

# **Typical Operating Performance** Unless otherwise noted: $V_{IN} = 5.4V$ , $V_{OUT} = 5.0V$ , $C_{IN} = C_{OUT} = 10 \mu F$ ,

 $T_J = +25$ °C,  $I_L = 0A$ . (Continued)

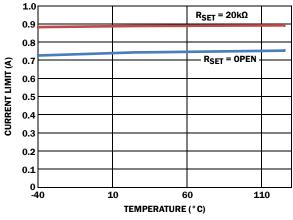


FIGURE 7. CURRENT LIMIT vs TEMPERATURE

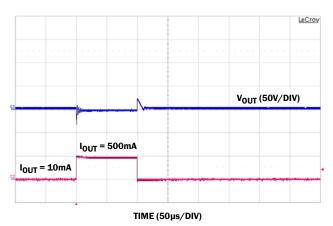


FIGURE 8. LOAD TRANSIENT RESPONSE

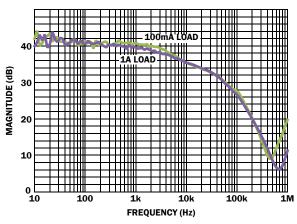


FIGURE 9. PSRR vs LOAD

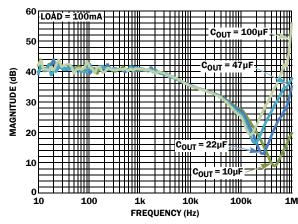


FIGURE 10. PSRR vs COUT

### **Functional Description**

#### **Input Voltage Requirements**

The ISL80121-5 is optimized for 5V output, and can operate from input voltages of 2.2V to 6V. Due to the nature of an LDO, VIN must be some margin higher than V<sub>OUT</sub> plus dropout at the maximum rated current of the application if active filtering (PSRR) is expected from V<sub>IN</sub> to V<sub>OUT</sub>. The generous dropout specification of this family of LDOs allows applications to design for a level of efficiency that can accommodate profiles smaller than the T0220/263.

#### **Programmable Current Limit**

The ISL80121-5 protects against overcurrent due to short-circuit and overload conditions applied to the output. When this happens, the LDO performs as a constant current source. If the short-circuit or overload condition is removed, the output returns to normal voltage regulation operation.

The current limit is set at 0.75A by default when the ISET pin is left floating.

This limit can be increased by tying a resistor R<sub>SET</sub> from the ISET pin to ground. The current limit is determined by R<sub>SET</sub> as shown in Equation 1:

$$\label{eq:limit} \textbf{I}_{\text{LIMIT}} \,=\, 0.75 + \frac{\textbf{2.9}}{\textbf{R}_{\text{SET}}(\textbf{k}\Omega)} \tag{EQ. 1}$$

Figure 11 shows the relationship between R<sub>SET</sub> and the current limit when the  $R_{\mbox{\footnotesize SET}}$  is tied from ISET pin to GND. Do not short this pin to ground. Increasing the current limit past 1.75A may cause damage to the part and is highly discouraged.

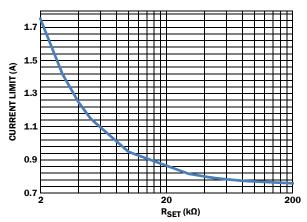


FIGURE 11. INCREASING ILIMIT (RSET TO GND)

The current limit can be decreased from the 0.75A default by tying R<sub>SET</sub> from the ISET pin to  $V_{IN}$ . The current limit is then determined by both R<sub>SET</sub> and  $V_{IN}$  following Equation 2:

$$I_{LIMIT} = 0.75 - \frac{2.9 \times (2 \times V_{IN} - 1)}{R_{SFT}(k\Omega)} \tag{EQ. 2} \label{eq:limit}$$

Figure 12 shows the relationship between  $R_{SET}$  and the current limit when  $R_{SET}$  is tied from the ISET pin to  $V_{IN}$  for  $V_{IN} = 5.4V$ .

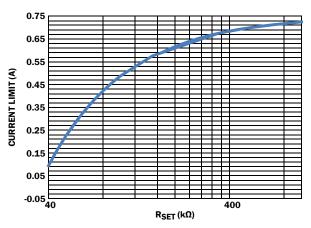


FIGURE 12. DECREASING I<sub>SET</sub> (R<sub>SET</sub> TO VIN)

#### **Enable Operation**

The Enable turn-on threshold is typically 800mV with 80mV of hysteresis. An internal pull-up or pull-down resistor to change these values is available upon request. As a result, this pin must not be left floating, and should be tied to  $\text{V}_{\text{IN}}$  if not used. A  $1\text{k}\Omega$  to  $10\text{k}\Omega$  pull-up resistor is required for applications that use open collector or open drain outputs to control the Enable pin. The Enable pin may be connected directly to  $\text{V}_{\text{IN}}$  for applications with outputs that are always on.

#### **Power-Good Operation**

PGOOD is a logic output that indicates the status of  $V_{OUT}$ , current limit tripping, and  $V_{IN}$ . The PGOOD flag is an open-drain NMOS that can sink up to 10mA during a fault condition. The PGOOD pin requires an external pull-up resistor typically connected to the VOUT pin. The PGOOD pin should not be pulled up to a voltage

source greater than  $V_{\text{IN}}$ . PGOOD goes low when the output voltage drops below 84% of the nominal output voltage, the current limit faults, or the input voltage is too low. PGOOD functions during shutdown, but not during thermal shutdown. For applications not using this feature, connect this pin to ground.

#### **Soft-Start Operation**

The soft-start circuit controls the rate at which the output voltage rises up to regulation at power-up or LDO enable. This start-up ramp time can be set by adding an external capacitor from the SS pin to ground. An internal  $2\mu A$  current source charges up this  $C_{SS}$  and the feedback reference voltage is clamped to the voltage across it. The start-up time is set by Equation 3:

$$\label{eq:tstart} \textbf{T}_{start} = \frac{(\textbf{C}_{SS}\textbf{x}\textbf{0.5})}{2\mu\textbf{A}} \tag{EQ. 3}$$

Equation 4 determines the  $C_{SS}$  required for a specific start-up in-rush current, where  $V_{OUT}$  is the output voltage,  $C_{OUT}$  is the total capacitance on the output and  $I_{INRUSH}$  is the desired in-rush current.

$$\label{eq:css} c_{\text{SS}} = \frac{(\text{V}_{\text{OUT}} \text{x} c_{\text{OUT}} \text{x} 2 \mu \text{A}))}{\text{I}_{\text{INRUSH}} \text{x} 0.5 \text{V}} \tag{EQ. 4}$$

The external capacitor is always discharged to ground at the beginning of start-up or enabling.

#### **External Capacitor Requirements**

External capacitors are required for proper operation. Careful attention must be paid to the layout guidelines and selection of capacitor type and value to ensure optimal performance.

#### **OUTPUT CAPACITOR**

The ISL80121-5 applies state-of-the-art internal compensation to keep the selection of the output capacitor simple for the customer. Stable operation over full temperature,  $V_{IN}$  range,  $V_{OUT}$  range and load extremes are guaranteed for all capacitor types and values assuming a minimum of  $10\mu F~X5R/X7R$  is used for local bypass on VOUT. This output capacitor must be connected to the VOUT and GND pins of the LDO with PCB traces no longer than 0.5cm.

There is a growing trend to use very-low ESR multilayer ceramic capacitors (MLCC) because they can support fast load transients and also bypass very high frequency noise from other sources. However, the effective capacitance of MLCCs drops with applied voltage, age, and temperature. X7R and X5R dieletric ceramic capacitors are strongly recommended as they typically maintain a capacitance range within ±20% of nominal voltage over full operating ratings of temperature and voltage.

Additional capacitors of any value in ceramic, POSCAP, alum/tantalum electrolytic types may be placed in parallel to improve PSRR at higher frequencies and/or load transient AC output voltage tolerances.

#### **INPUT CAPACITOR**

For proper operation, a minimum capacitance of  $10\mu F$  X5R/X7R is required at the input. This ceramic input capacitor must be connected to the VIN and GND pins of the LDO with PCB traces no longer than 0.5cm.

#### **Power Dissipation and Thermals**

The junction temperature must not exceed the range specified in the "Recommended Operating Conditions" on page 4. The power dissipation can be calculated by using Equation 5:

$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{GND}$$
 (EQ. 5)

The maximum allowable junction temperature,  $T_{J(MAX)}$  and the maximum expected ambient temperature,  $T_{A(MAX)}$  determine the maximum allowable power dissipation, as shown in Equation 6:

$$P_{D(MAX)} = (T_{J(MAX)} - T_{A})/\theta_{JA}$$
 (EQ. 6)

 $\theta_{\text{IA}}$  is the junction-to-ambient thermal resistance.

For safe operation, enure that the power dissipation  $P_D$ , calculated from Equation 5, is less than the maximum allowable power dissipation  $P_{D(MAX)}$ .

The DFN package uses the copper area on the PCB as a heat-sink. The EPAD of this package must be soldered to the copper plane (GND plane). Figure 13 shows a curve for the  $\theta_{JA}$  of the DFN package for different copper area sizes.

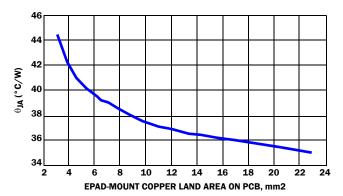


FIGURE 13. 3mmx3mm 10 LD DFN ON 4-LAYER PCB WITH THERMAL VIAS  $\theta_{1A}$  vs EPAD-MOUNT COPPER LAND AREA ON PCB

#### **Thermal Fault Protection**

The power level and the thermal impedance of the package (+48 °C/W for DFN) determine when the junction temperature exceeds the thermal shutdown temperature. In the event that the die temperature exceeds around +160 °C, the output of the LDO will shut down until the die temperature cools down to about +130 °C.

### **Revision History**

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision.

DATE	REVISION	CHANGE
12/6/10	FN7713.1	1. In "Block Diagram" on page 2: a. Added "ADJ adjustable voltage version" Pin. Added "fixed voltage version" to "SENSE" pin 2. On page 4: "Ground Pin Current" Test Conditions a. Replaced "V <sub>OUT</sub> +0.4V" with "2.2V" on both lines
12/2/10	FN7713.0	Initial Release.

### **Products**

Intersil Corporation is a leader in the design and manufacture of high-performance analog semiconductors. The Company's products address some of the industry's fastest growing markets, such as, flat panel displays, cell phones, handheld products, and notebooks. Intersil's product families address power management and analog signal processing functions. Go to <a href="https://www.intersil.com/products">www.intersil.com/products</a> for a complete list of Intersil product families.

\*For a complete listing of Applications, Related Documentation and Related Parts, please see the respective device information page on intersil.com: ISL80121-5

To report errors or suggestions for this datasheet, please go to: www.intersil.com/askourstaff

FITs are available from our website at: http://rel.intersil.com/reports/sear

For additional products, see <a href="www.intersil.com/product-tree">www.intersil.com/product-tree</a>

Intersil products are manufactured, assembled and tested utilizing ISO9000 quality systems as noted in the quality certifications found at www.intersil.com/design/quality

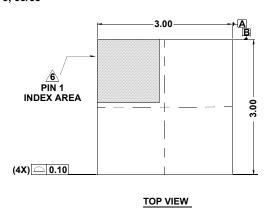
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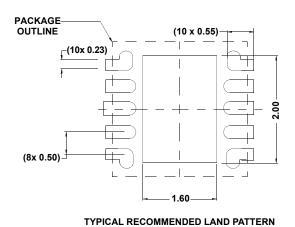
For information regarding Intersil Corporation and its products, see www.intersil.com

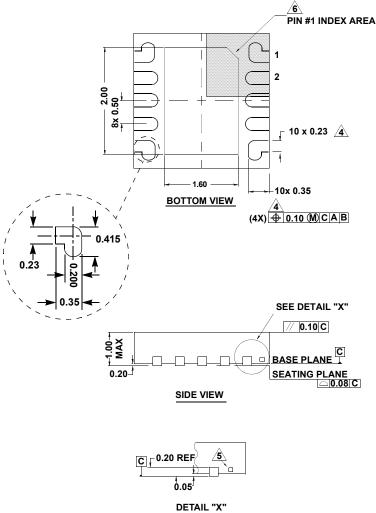
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### **Package Outline Drawing**

# L10.3x3 10 LEAD DUAL FLAT PACKAGE (DFN) Rev 6, 09/09







#### NOTES:

- Dimensions are in millimeters.
   Dimensions in ( ) for Reference Only.
- 2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
- 3. Unless otherwise specified, tolerance : Decimal  $\pm$  0.05
- Lead width applies to the metallized terminal and is measured between 0.18mm and 0.30mm from the terminal tip.
- 5. Tiebar shown (if present) is a non-functional feature.
- The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 indentifier may be either a mold or mark feature.